

**66163**

**SINGLE CHANNEL OPTOCOUPLED  
DIRECT REPLACEMENT FOR 3C91C**



**Features:**

- High Reliability
- Base lead eliminated for improved noise immunity
- Rugged package
- Stability over wide temperature
- +500V electrical isolation

**Applications:**

- Eliminate ground loops
- Level shifting
- Line receiver
- Switching power supplies
- Motor control

**DESCRIPTION**

The **66163** contains a gallium arsenide infrared LED optically coupled to a silicon planar phototransistor. The optocoupler is built on a TO-46 header. The collector of the phototransistor is electrically connected to the case. This optocoupler is capable of transmitting signals between two galvanic sources. The potential difference between transmitter and receiver should not go over the maximum isolation voltage. The internal base connection has been eliminated for improved noise immunity.

**ABSOLUTE MAXIMUM RATINGS**

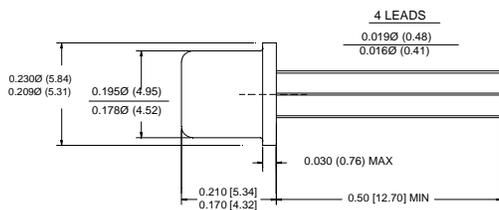
|  |                 |
|--|-----------------|
| Input to Output Voltage .....  | 500V            |
| Emitter-Collector Voltage .....  | 5V              |
| Collector-Emitter Voltage (Value applies to emitter-base open-circuited & the input-diode equal to zero) ..... | 60V             |
| Reverse Input Voltage .....  | 7V              |
| Input Diode Continuous Forward Current at (or below) 65°C Free-Air Temperature (see note 1) .....              | 50mA            |
| Peak Forward Input Current (Value applies for $t_w \leq 1\mu s$ , PRR < 300 pps) .....                         | 50mA            |
| Continuous Collector Current.....  | 50mA            |
| Continuous Transistor Power Dissipation at (or below) 25°C Free-Air Temperature (see Note 2) .....             | 300mW           |
| Storage Temperature .....  | -65°C to +150°C |
| Operating Free-Air Temperature Range.....  | -55°C to +100°C |
| Lead Solder Temperature (10 seconds max.) .....  | 240°C           |

**Notes:**

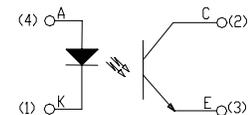
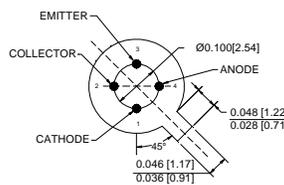
1. Derate linearly to 125°C free-air temperature at the rate of 0.67 mA/°C above 65°C.
2. Derate linearly to 125°C free-air temperature at the rate of 3 mW/°C.

**Package Dimensions**

**Schematic Diagram**



DIMENSIONS ARE IN INCHES (MILLIMETERS)



NOTE: ANODE ELECTRICALLY CONNECTED TO CASE

# 66163

## SINGLE CHANNEL OPTOCOUPLER (Direct Replacement for 3C91C)

### ELECTRICAL CHARACTERISTICS

T<sub>A</sub> = 25°C unless otherwise specified.

| PARAMETER                          | SYMBOL          | MIN | TYP  | MAX | UNITS | TEST CONDITIONS        |
|------------------------------------|-----------------|-----|------|-----|-------|------------------------|
| Input Diode Static Reverse Current | I <sub>R</sub>  |     |      | 1   | μA    | V <sub>R</sub> = 3V    |
| Input Diode Static Forward Voltage | V <sub>F</sub>  |     | 1.15 | 1.2 | V     | I <sub>F</sub> = 2mA   |
| Input Diode Static Forward Voltage | V <sub>F</sub>  |     | 1.3  | 1.5 | V     | I <sub>F</sub> = 50mA  |
| Reverse Breakdown Voltage          | B <sub>VR</sub> | 7   | 12   |     | V     | I <sub>R</sub> = 100μA |
| Input Diode Capacitance            | C <sub>IN</sub> |     | 25   |     | pF    | V = 0V, f = 1MHz       |

### OUTPUT TRANSISTOR

T<sub>A</sub> = 25°C unless otherwise specified.

| PARAMETER                           | SYMBOL                                 | MIN | TYP | MAX      | UNITS | TEST CONDITIONS   |
|-------------------------------------|--|-----|-----|----------|-------|---|
| Collector-Emitter Breakdown Voltage | V <sub>(BR)CEO</sub>                   | 50  |     |          | V     | I <sub>C</sub> = 1mA, I <sub>B</sub> = 0, I <sub>F</sub> = 0                              |
| Emitter-Collector Breakdown Voltage | V <sub>(BR)ECO</sub>                   | 5   |     |          | V     | I <sub>C</sub> = 0mA, I <sub>E</sub> = 10μA, I <sub>F</sub> = 0                           |
| Collector-Emitter Dark Current      | I <sub>CEO1</sub><br>I <sub>CEO2</sub> |     |     | 60<br>10 | nA    | V <sub>CE</sub> = 50V, I <sub>F</sub> = 0mA<br>V <sub>CE</sub> = 5V, I <sub>F</sub> = 0mA |

### COUPLED CHARACTERISTICS

T<sub>A</sub> = 25°C unless otherwise specified.

| PARAMETER                            | SYMBOL               | MIN             | TYP | MAX | UNITS | TEST CONDITIONS   |
|--------------------------------------|----------------------|-----------------|-----|-----|-------|---|
| On State Collector Current           | I <sub>C(ON)</sub>   | 4               |     |     | mA    | V <sub>CE</sub> = 5V, I <sub>F</sub> = 10mA                       |
| On State Collector Current           | I <sub>C(ON)</sub>   | 3               |     |     | mA    | V <sub>CE</sub> = 0.4V, I <sub>F</sub> = 10mA                     |
| On State Collector Current           | I <sub>C(ON)</sub>   | 2               |     |     | mA    | V <sub>CE</sub> = 5V, I <sub>F</sub> = 10mA                       |
| On State Collector Current           | I <sub>C(ON)</sub>   | 20              |     |     | mA    | V <sub>CE</sub> = 5V, I <sub>F</sub> = 10mA                       |
| Collector-Emitter Saturation Voltage | V <sub>CE(SAT)</sub> |                 |     | 0.4 | V     | I <sub>F</sub> = 50mA, I <sub>C</sub> = 10mA                      |
| Isolation Resistance                 | R <sub>ISO</sub>     | 10 <sup>9</sup> |     |     | Ω     | V <sub>IN-OUT</sub> = 500V  |
| Input to Output Capacitance          | C <sub>IO</sub>      |                 | 2   | 2.5 | pF    | f = 1MHz  |
| Delay Time                           | t <sub>d</sub>       |                 | 2   | 4   | μs    | V <sub>CE</sub> = 5V, I <sub>F</sub> = 2mA, R <sub>L</sub> = 100Ω |
| Storage Time                         | t <sub>s</sub>       |                 | 0.2 | 0.5 | μs    | V <sub>CE</sub> = 5V, I <sub>F</sub> = 2mA, R <sub>L</sub> = 100Ω |
| Rise Time                            | t <sub>r</sub>       |                 | 3   | 5   | μs    | V <sub>CE</sub> = 5V, I <sub>F</sub> = 2mA, R <sub>L</sub> = 100Ω |
| Fall Time                            | t <sub>f</sub>       |                 | 4   | 5   | μs    | V <sub>CE</sub> = 5V, I <sub>F</sub> = 2mA, R <sub>L</sub> = 100Ω |

### RECOMMENDED OPERATING CONDITIONS:

| PARAMETER                 | SYMBOL          | MIN | MAX | UNITS |
|---------------------------|-----------------|-----|-----|-------|
| Input Current, Low Level  | I <sub>FL</sub> | 0   | 1   | μA    |
| Input Current, High Level | I <sub>FH</sub> | 2   | 10  | mA    |
| Supply Voltage            | V <sub>CE</sub> | 5   | 50  | V     |
| Operating Temperature     | T <sub>A</sub>  | -55 | 125 | °C    |

### SELECTION GUIDE

| PART NUMBER | PART DESCRIPTION   |
|-------------|--|
| 66163-001   | Single Channel optocoupler, commercial (0° to 70°C)  |
| 66163-011   | Single Channel optocoupler full military operating temperature range   |
| 66163-101   | Single Channel optocoupler tested over full military temperature range with 100% device screening            |
| 66163-017   | Single Channel optocoupler full military operating temperature range w/200% CTR                              |
| 66163-107   | Single Channel optocoupler tested over full military temperature range with 100% device screening w/200% CTR |